## NSN 5961-00-983-9482

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View Online at https://aerobasegroup.com/nsn/5961-00-983-9482
Inclosure Material:
Metal
Overall Length:
0.400 inches
Mounting Facility Quantity:
1
Internal Configuration:
Junction contact
Mounting Method:
Threaded stud
Overall Width Across Flats:
0.437 inches
Thread Size:
0.190 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
10.0 reverse gate to source voltage and 10.0 forward gate to source breakdown voltage
Current Rating Per Characteristic:
2.00 amperes forward current, total rms of standard range
Power Rating Per Characteristic:
5.0 watts small-signal input power, common-collector blank
Maximum Operating Tempurature Per Measurement Point:
125.0 degrees celsius ambient air
Special Features:
Junction pattern arrangement: pnpn
Thread Series Designator:
Unf
Terminal Type And Quantity:
1 threaded stud and 2 tab, solder lug
Shelf Life:
N/a
Unit Of Measure:
<del></del>
Demilitarization:
No
Fiig:
A110a0